Electrostatic characterization of tips for NC-AFM

J. Evers, 1,* D. Heile, P. Rahe, and M. Reichling

The quantitative interpretation of non-contact atomic force microscopy (NC-AFM) results, including images, force curves, potential as well as charge measurements, critically depends on the shape and dimensions of the tip. Here, we address the challenge of a reliable and reproducible characterization of parameters describing the experimental tip-sample system, such as tip radius R_{tip} and absolute tip-sample distance offset δz , taking into account electrostatic interactions. Our approach involves a measurement routine for the capacitance gradient $\partial C_{void} / \partial z_{tip}$. Here the capacitance gradient between a sharp PtIr-coated silicon cantilever tip and metal(-oxide) surfaces as a function of tip-sample distance as shown in figure 1(a-d) and a fit to an finite-difference method (FDM) based electrostatic model is investigated. 1,2 The capacitance gradient is measured from the frequency component at f₀±2f_{el} when modulating the bias voltage at frequency fel. We discuss approaches to remedy imprecisions that are inherent to this measurement approach. To demonstrate the robustness of this approach, we systematically acquire the distance-dependent capacitance signal on a conducting Cu(111) surface with an ideally infinite permittivity ε_s and a semiconductor $TiO_2(101)$ surface with a moderate permittivity $\varepsilon_s = 90$ F/m, using the same tip. Both measurements yield comparable fit results, with a tip-sample distance offset of 2.0 nm and a tip radius of 7.2 nm for TiO₂ and 7.9 nm for Cu.

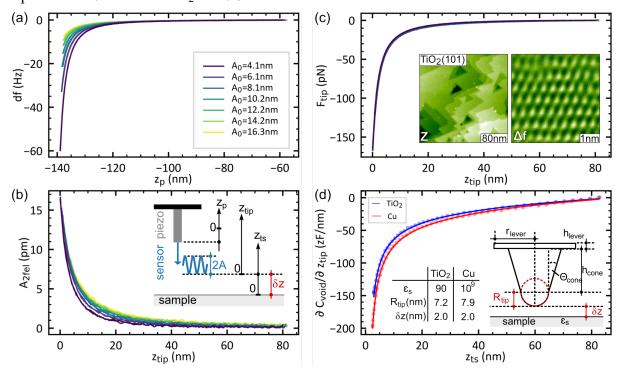


Figure 1. (a,b) Distance-dependent measurements showing the frequency shift and $A_{2\text{fel}}$ signal. (inset b) Representation of different z-axis describing the tip-sample system. (c,d) Deconvolved force and capacitance gradient curves, from which the tip radius R_{tip} and the absolute tip-sample distance δz are determined by fitting an electrostatic model to the latter data. (inset d) Tip geometry used in the electrostatic model. Fixed parameters are marked in black, the two fit parameters in red.

- [1] Heile, et al. Phys. Rev. B 108, 085420 (2023)
- [2] Sadeghi, et al. Phys. Rev. B 86, 075407 (2012)

¹Universität Osnabrück, Osnabrück, 49076, Germany

^{*} jannik.evers@uni-osnabrueck.de